

Low Noise TCXO, Vibration Compensated

50MHz to 100MHz

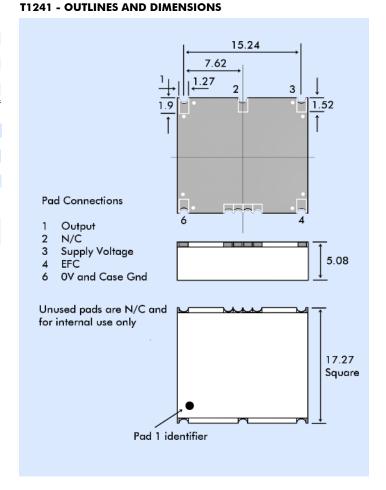
- Rugged construction for severe environments
- Electrically compensated for vibration
- Frequency Range: 50MHz 100MHz
- Tight temperature stability, from ±2ppm over -40° to +85°C
- Output Signal: CMOS Squarewave





SPECIFICATIONS

Frequency Range:	50MHz to 100MHz	
Output:	CMOS into 15pF load±10%	
Symmetry:	50% ±10%	
Rise/Fall Time:	≤10ns	
Frequency Stability:	±2x10-6 over -40° to +85°C	
	Ramp rate of up to 2°/minute. Shall meet spec within 1 minute of turn on.	
Frequency vs. Supply:	±3x10 ⁻⁷ for a 5% change	
Ageing:	<1.0ppm/year	
Supply Voltage:	+3.3VDC or +5.0VDC±5%	
Input Current:	30mA maximum	
Phase Noise:	See table	
Acceleration Sensitivity:	≤7x10-10/g in the worst axis (SD option)	
,	≤7x10-11/g in the worst axis (LG option)	
Frequency Adjust:	±5.0ppm typical, positive slope 0V to Vsupply EFC	



PHASE NOISE

Offset	dBc/Hz
10Hz	-70
100Hz	-100
1kHz	-135
10kHz	-155
100kHz	-160

Floor = -165dBc/Hz

ENVIRONMENTAL

Vibration:	per MIL-STD-202F, Meth. 214, Cond. I-F
Shock:	per MIL-STD-202F, Meth. 213, Cond K
Storage Temperature:	-55° to +95°C

PART NUMBERING

Example: **T1241-3.3-LG-100.0MHz**

